

26/01/2018 – ICFO

**Semi-synthetic
topological
quantum matter**

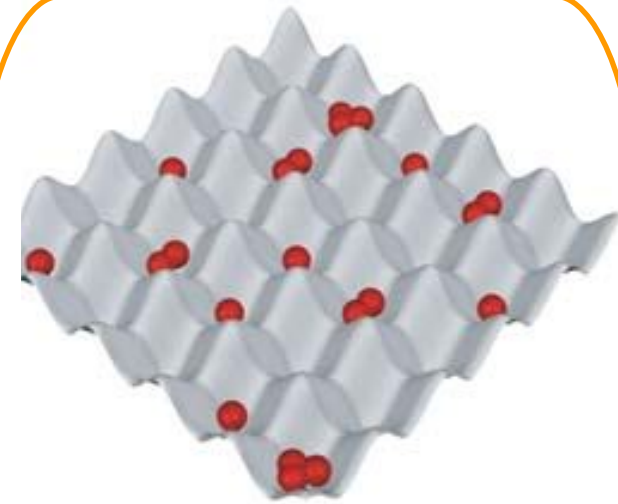
Tobias Grass (JQI)



Real matter

with relevant features intrinsic to the material

- Solid state materials with intrinsic electronic properties:
 - semiconductors
 - semimetals
 - metals
 - insulators ...
- Topological features:
 - topological insulators
 - quantum Hall samples (require external field)



Synthetic matter

for which these features must be generated artificially

- Quantum simulators: usually AMO systems in which light-matter interactions create some features (e.g. atomic gas in lattice potential)
- Topological synthetic matter: artificial gauge fields



Real matter

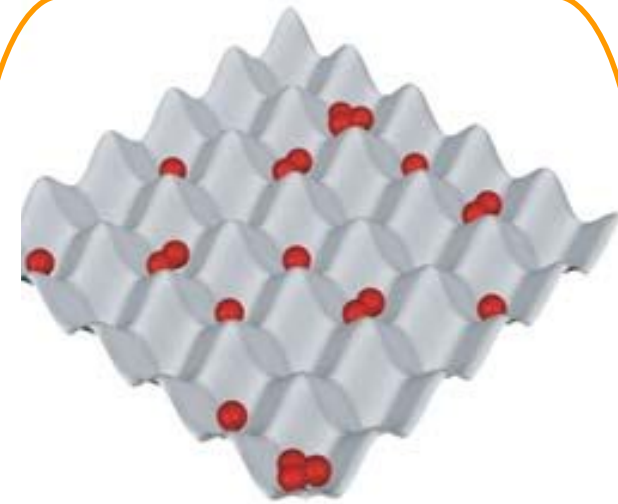
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Semi-synthetic matter

Enrich real matter with artificial features

- Floquet topological insulator:
PHYSICAL REVIEW B 79, 081406(R) (2009)
Photovoltaic Hall effect in graphene
Takashi Oka and Hideo Aoki
See also experiments at MIT [Gedik group]
- Light-induced superconductivity in cuprates [Cavalleri group]
- This talk: Light-induced quantum Hall phases in graphene



Synthetic matter

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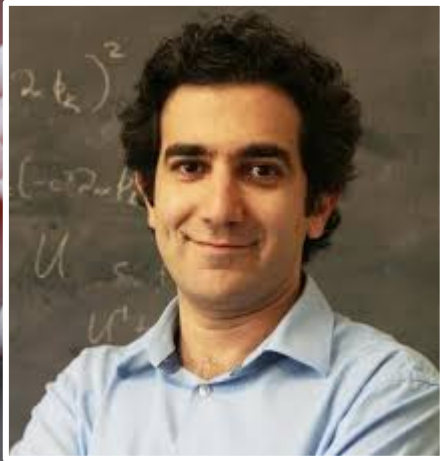
Outline

Intro: Quantum Hall, Graphene,
Light-matter coupling

Part I: Optical driving:
Controlling FQH phases

Part II: Optical excitations:
Flux pump and braiding

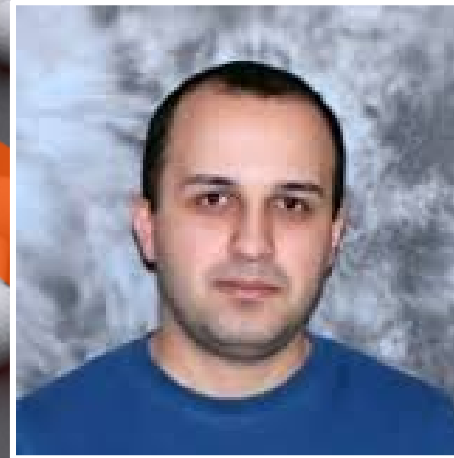
Work in collaboration with:



Mohammad Hafezi
(JQI / NIST)



Michael Gullans
(Princeton)



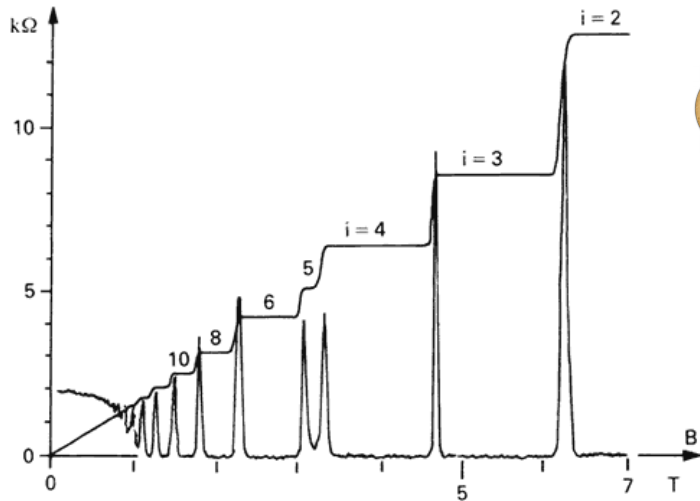
Areg Ghazaryan
(City College New York)



Pouyan Ghaemi
(City College New York)

Quantum Hall Effect

As transport phenomenon: Quantized Hall Resistance



1985



Klaus v. Klitzing

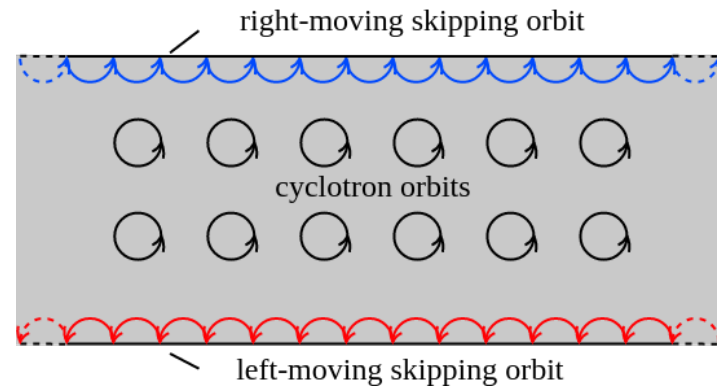
Explanation in terms of topology: Protected Edge States



2016



David Thouless



Fractional Quantum Hall Effect and Anyonic Quasiparticles

$$\Psi_{\text{Laughlin}} = \prod_{i < j} (z_i - z_j)^{1/\nu} e^{-\sum_i |z_i|^2 / 4}$$



1998



Robert B. Laughlin
Prize share: 1/3

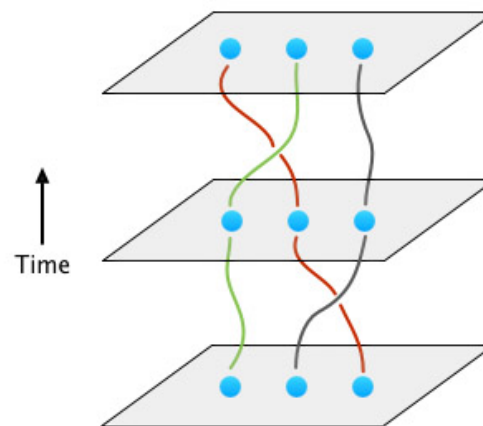


Horst L. Störmer
Prize share: 1/3



Daniel C. Tsui
Prize share: 1/3

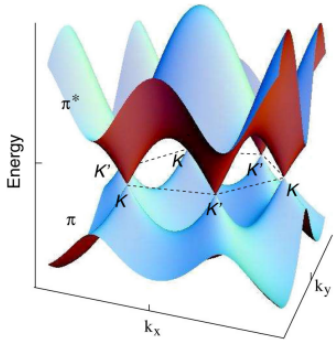
Non-Abelian Anyons and Topological Quantum Computing



Use non-Abelian anyons as robust quantum memory. Quantum information is processed by braiding these anyons.

NO NOBEL PRIZE YET!!

Graphene in magnetic field: Landau levels



Effective Hamiltonian around Dirac point:

$$H_\xi = \xi v_F (p_x \sigma_x + p_y \sigma_y)$$

$$\xi = \pm \text{ for } K, K'$$

Pauli matrices represent sublattice structure!

In magnetic field:

$$p_i \rightarrow \Pi_i = p_i - \frac{e}{c} A_i$$

$$\Pi_x = \frac{\hbar}{\sqrt{2} l_B} (a^\dagger + a) \quad \text{and} \quad \Pi_y = \frac{\hbar}{i\sqrt{2} l_B} (a^\dagger - a)$$

$$H_\xi = \xi \sqrt{2} \frac{\hbar v_F}{l_B} \begin{pmatrix} 0 & a \\ a^\dagger & 0 \end{pmatrix}$$

“Standard” Landau level wave functions:

$$a^\dagger \varphi_{n,m} = \varphi_{n+1,m}$$

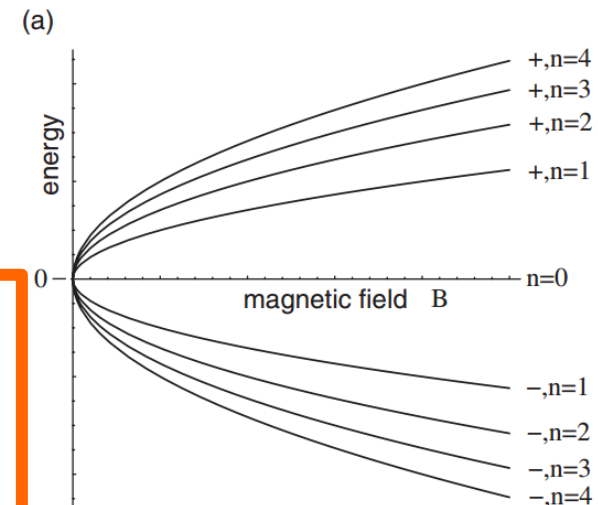
Graphene Landau level wave functions:

$$\Psi_{n=0,m} = \begin{pmatrix} 0 \\ \varphi_{0,m} \end{pmatrix} \quad \text{and} \quad \Psi_{n \neq 0,m} = \frac{1}{\sqrt{2}} \begin{pmatrix} \varphi_{|n|-1,m} \\ \xi \text{sign}(n) \varphi_{|n|,m} \end{pmatrix}$$

At energies $\epsilon_n = \text{sign}(n) \frac{\hbar v_F}{l_B} \sqrt{2|n|}$

Features of relativistic Landau levels:

- Spinor wave function
- Spin and valley degeneracy: 4 bands per energy level
- Particle-hole symmetry
- Non-equidistant energy levels!



Interactions between light and Landau levels

Dirac Hamiltonian:

$$H = v_F(p_x \sigma_x + p_y \sigma_y)$$

Minimal coupling:

$$p_i \rightarrow \Pi_i = p_i - \frac{e}{c} A_i$$

Light-matter interaction:

$$H_{\text{int}} \sim \sigma_{\pm} A_{\pm}(x, y, t) + \text{h.c.}$$

Example. circularly polarized plane-wave in x-direction:

$$\mathbf{A}(x, y, t) \sim \exp[i(kx - \omega t)] \begin{pmatrix} 1 \\ \pm i \end{pmatrix} + \text{h.c.}$$

rotating frame: $(\langle \tilde{n} - 1, \tilde{m} |, \langle \tilde{n}, \tilde{m} |) H_{\text{int}} \begin{pmatrix} 0 \\ |0, m\rangle \end{pmatrix} \sim (\langle \tilde{n} - 1, \tilde{m} |, \langle \tilde{n}, \tilde{m} |) \exp[\pm ikx] \begin{pmatrix} |0, m\rangle \\ 0 \end{pmatrix}$

The transition matrix element of non-relativistic Landau levels is given by:

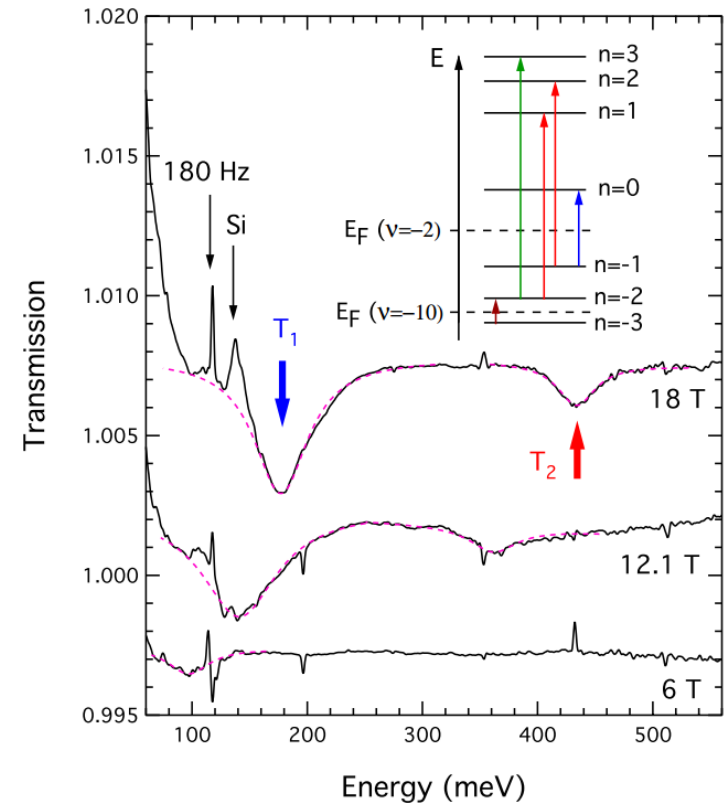
$$\int d^2z \varphi_{\tilde{n}, \tilde{m}}(z)^* \varphi_{n, m}(z) e^{\pm ikx} = \sqrt{\frac{n! m!}{\tilde{n}! \tilde{m}!}} (\pm ik)^{\tilde{n}-n} L_{\tilde{n}-n}^{\tilde{n}-n}(k^2) L_m^{\tilde{m}-m}(k^2)$$

It is dominated by: $\tilde{n} = n$ and $\tilde{m} = m$

Thus, in terms of relativistic LL spinors, the optical selection rules are:

$$\tilde{n} = |n| \pm 1 \quad \text{and} \quad m = \tilde{m}$$

m-selection rule can be modified by using light with OAM, cf. M. Gullans *et al.*, PRB 95, 235439 (2017).





Part I: Optical driving: Controlling FQH phases

Light-Induced Fractional Quantum Hall Phases in Graphene

Areg Ghazaryan, Tobias Graß, Michael J. Gullans, Pouyan Ghaemi, and Mohammad Hafezi

Phys. Rev. Lett. 119, 247403 – Published 15 December 2017

Coupled Landau levels

$$H_0(t) = \sum_m \left[\frac{\Delta E}{2} \left(c_{n+1,m}^\dagger c_{n+1,m} - c_{n,m}^\dagger c_{n,m} \right) + \hbar\Omega \left(c_{n+1,m}^\dagger c_{n,m} e^{-i(\Delta E - \delta)t} + \text{h.c.} \right) \right]$$

In rotating frame after rotating wave approximation

$$H_0 = \sum_m \left[\hbar\delta c_{n+1,m}^\dagger c_{n+1,m} + \hbar\Omega c_{n+1,m}^\dagger c_{n,m} \right] + \text{h.c.}$$

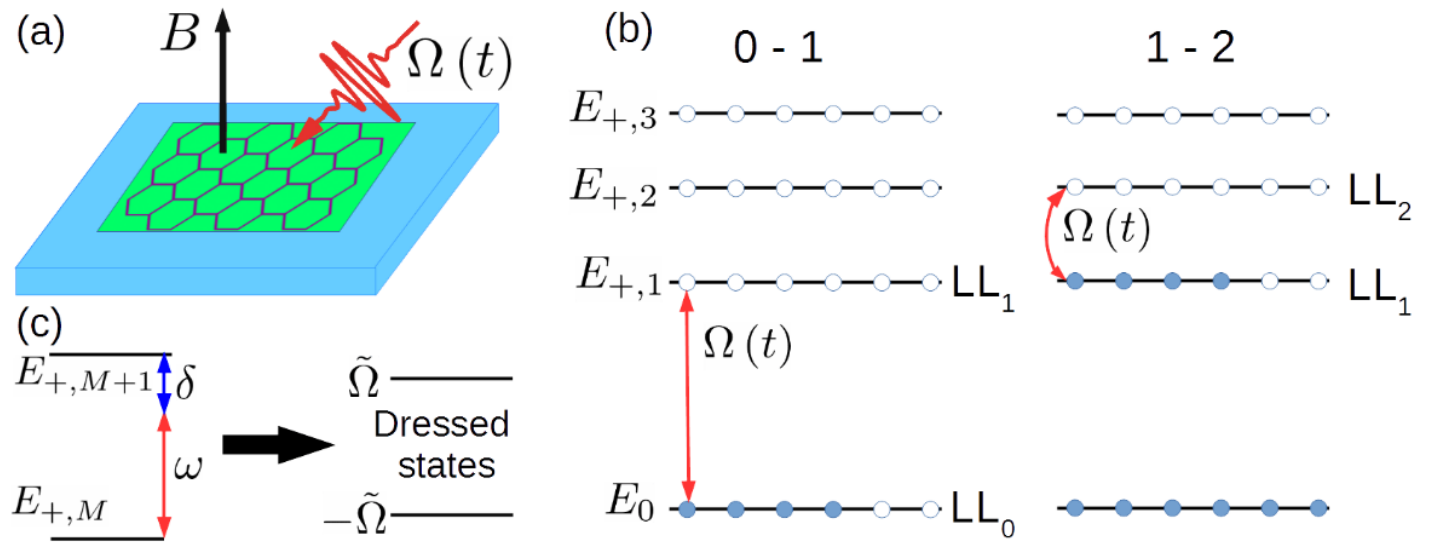
Less is more!

Strong coupling:

Lowest Landau level becomes dressed, but may not change much the physics.

Weak coupling:

Both Landau levels can be occupied: System becomes analogous to a bilayer.



Interactions between coupled LLs

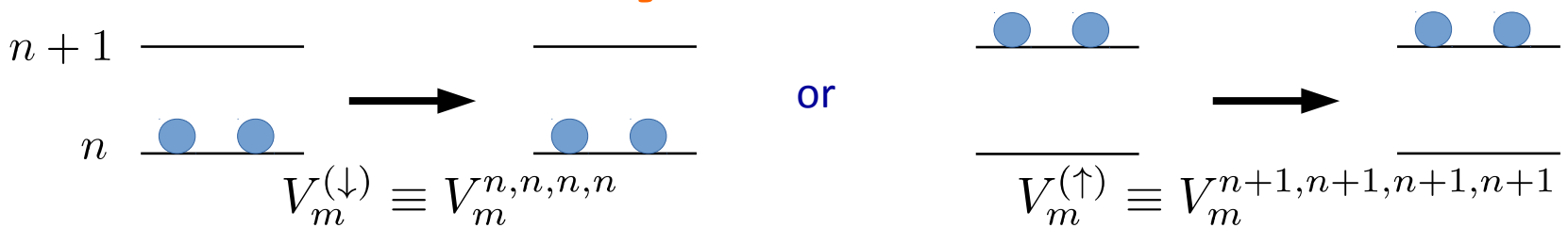
Fractional Quantum Hall Hamiltonian: $H = H_0 + V^{(\text{RWA})}$

$$V_{m_1, m_2, m_3, m_4}^{n_1, n_2, n_3, n_4 (\text{RWA})} = \delta_{n_1 + n_2 - n_3 - n_4} V_{m_1, m_2, m_3, m_4}^{n_1, n_2, n_3, n_4}$$

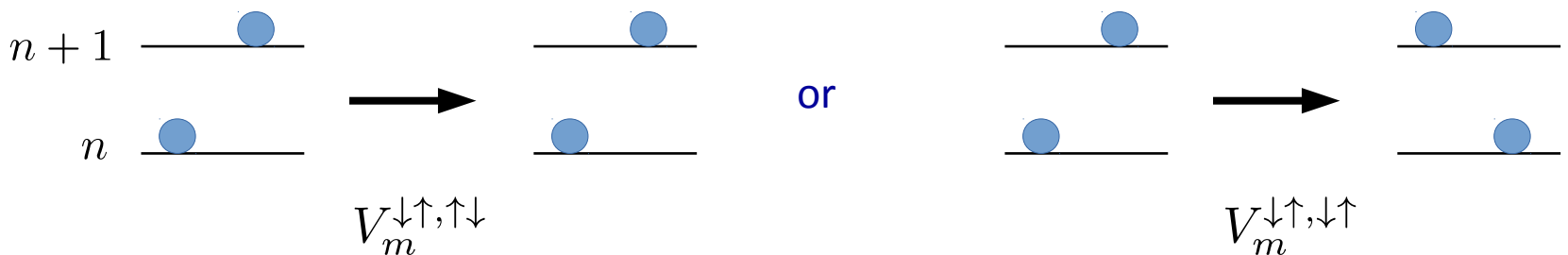
Pseudopotential expansion: $V_{m_1, m_2, m_3, m_4}^{n_1, n_2, n_3, n_4} = \sum_{m, M} V_m^{n_1, n_2, n_3, n_4} \langle m_1, m_2 | m, M \rangle \langle m, M | m_3, m_4 \rangle$

Different kinds of interaction processes:

(I) “Intra-layer” interactions



(II) “Inter-layer” interactions



Interactions between coupled LLs

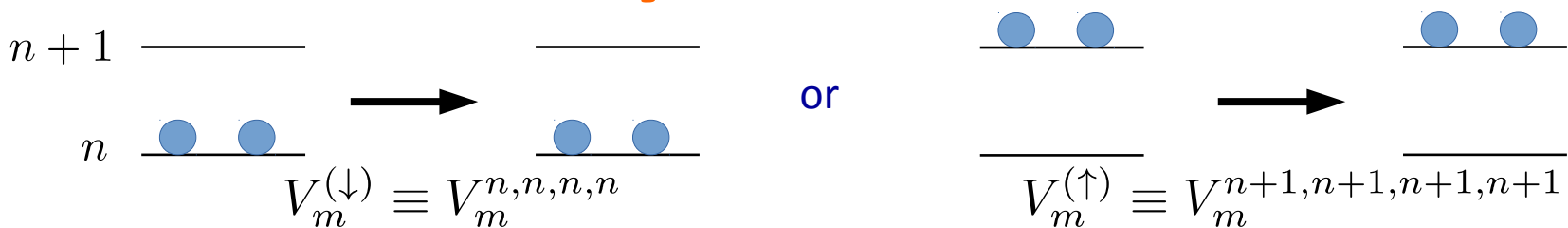
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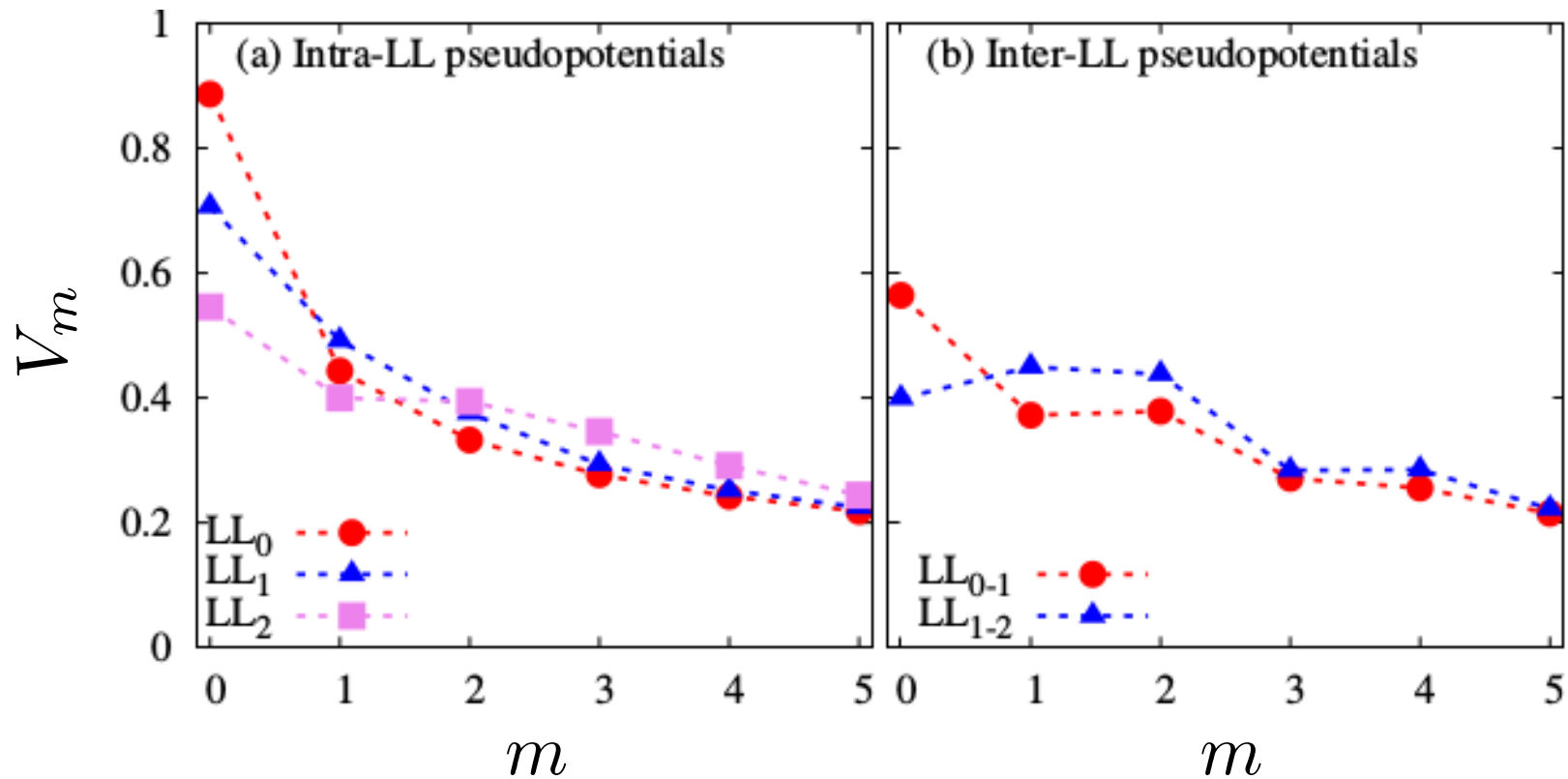


(II) “Inter-layer” interactions

$$V_m^{(\text{singlet})} \equiv \langle \uparrow\downarrow - \downarrow\uparrow | V_m | \uparrow\downarrow - \downarrow\uparrow \rangle = \frac{1}{2} (V_m^{\uparrow\downarrow, \downarrow\uparrow} - V_m^{\uparrow\downarrow, \uparrow\downarrow}) \quad \text{requires even } m$$

$$V_m^{(\text{triplet})} \equiv \langle \uparrow\downarrow + \downarrow\uparrow | V_m | \uparrow\downarrow + \downarrow\uparrow \rangle = \frac{1}{2} (V_m^{\uparrow\downarrow, \downarrow\uparrow} + V_m^{\uparrow\downarrow, \uparrow\downarrow}) \quad \text{requires odd } m$$

Interactions between coupled LLs



(a) Intra-layer pseudopotentials for different graphene LLs

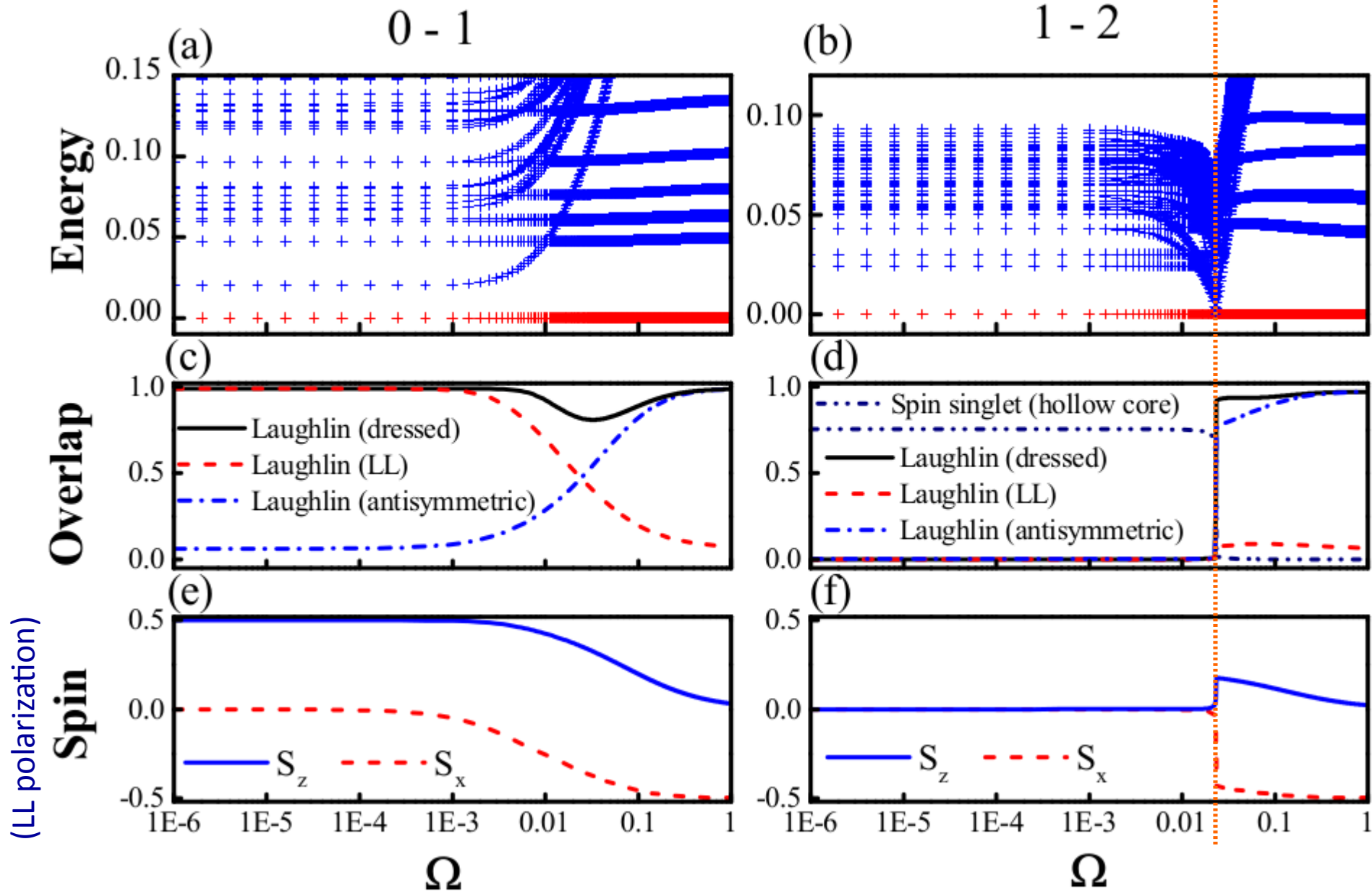
(b) Inter-layer pseudopotentials when $n=0$ graphene LL is coupled to $n=1$ (red), or $n=1$ is coupled to $n=2$ (blue).

Coupling 1-2 favors singlets at $m=0$ over triplets at $m=1$. We thus expect a tendency towards singlet ground states, maybe phases described by a hollow-core model?

LL 0-1 coupling vs. LL 1-2 coupling

Exact diagonalization results for $N=8$ electrons on a torus at filling $\nu=2/3$:

Phase transition:
Polarized vs. singlet phase



LL 1-2 coupling: Singlet vs. polarized phase

Singlet
phase

Polarized
phase

$$\nu = 2/3$$

Laughlin state
of holes

$$\nu = 1/2$$

Composite Fermi sea
(Halperin, Lee, Read)

Ω

LL 1-2 coupling: Singlet vs. polarized phase

Singlet phase

Polarized phase

$$\nu = 2/3$$

- Intra-layer Pfaffian
- Inter-layer Pfaffian
- Fibonacci
- (113)-Halperin
- (330)-Halperin
- CF singlet

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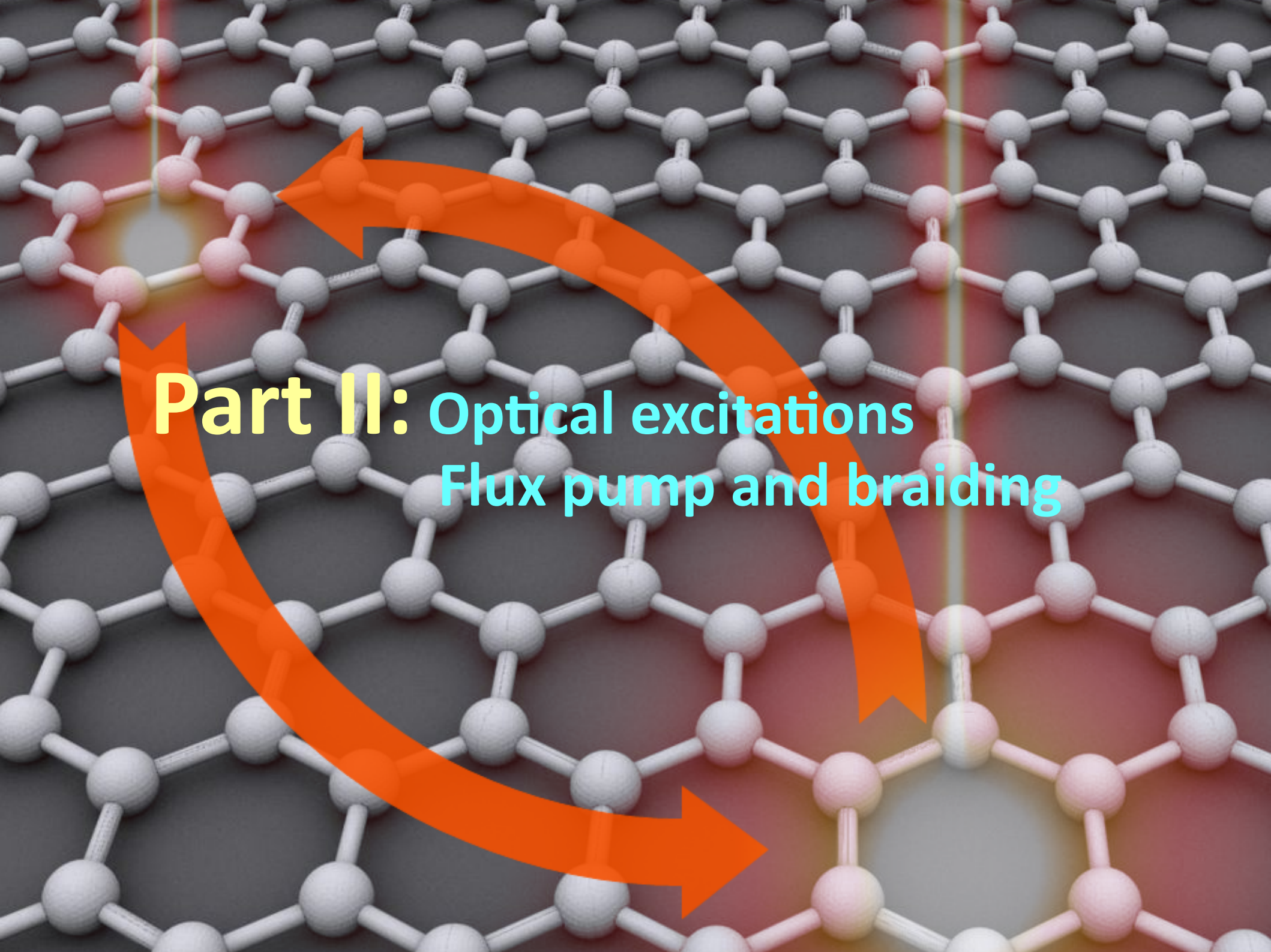
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Composite Fermi sea
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Ω



Part II: Optical excitations
Flux pump and braiding

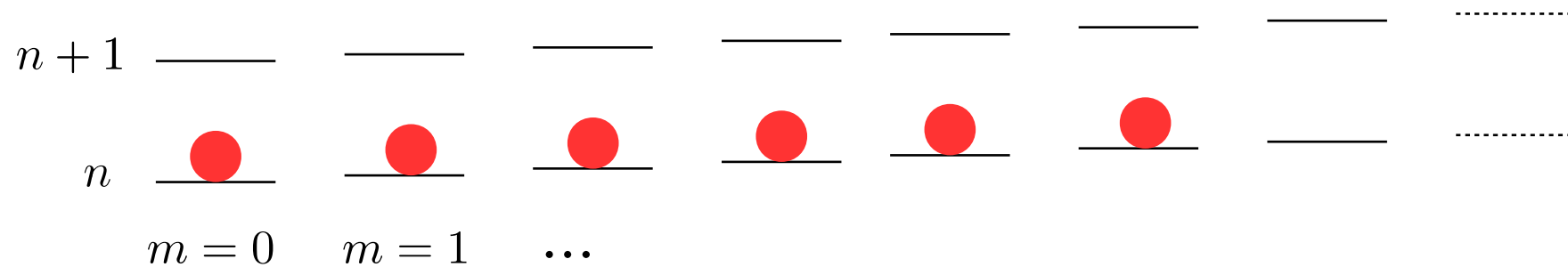
π -pulse excitations

Single-particle level: π -pulse flips spin.

In terms of Landau levels: $\varphi_{n,m} \rightarrow \varphi_{n+1,m} = a^\dagger \varphi_{n,m}$

Pulse with OAM: $\varphi_{n,m} \rightarrow \varphi_{n+1,m+1} = a^\dagger b^\dagger \varphi_{n,m}$

Action onto an IQH phase:



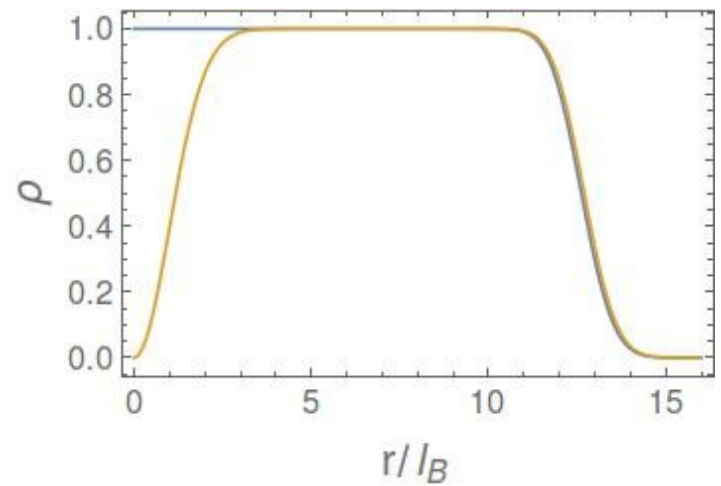
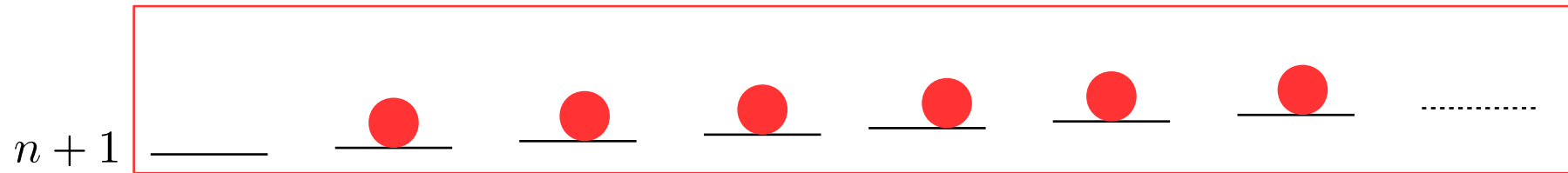
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Action onto an IQH phase:



Density of IQH and hole, for $N=100$ within $n=0$ LL.

IQH with hole in the center

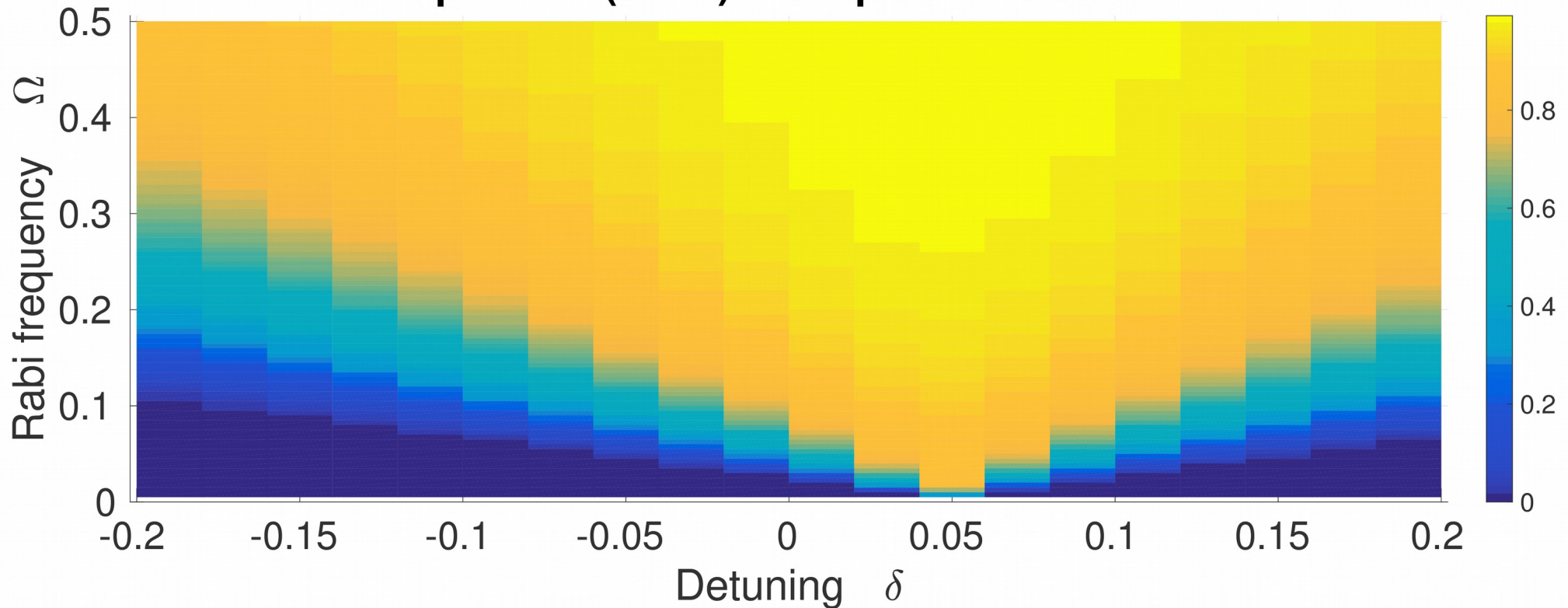
π -pulse: Many-body excitations

Action of a pulse on many-body wave function in the LLL:

$$\Psi \rightarrow \prod_{i=1}^N a_i^\dagger b_i^\dagger \Psi = \prod_{i=1}^N a_i^\dagger \left(\prod_{i=1}^N z_i \Psi \right)$$

Fidelity of pi-pulse in the presence of Coulomb interactions ($N=5$):

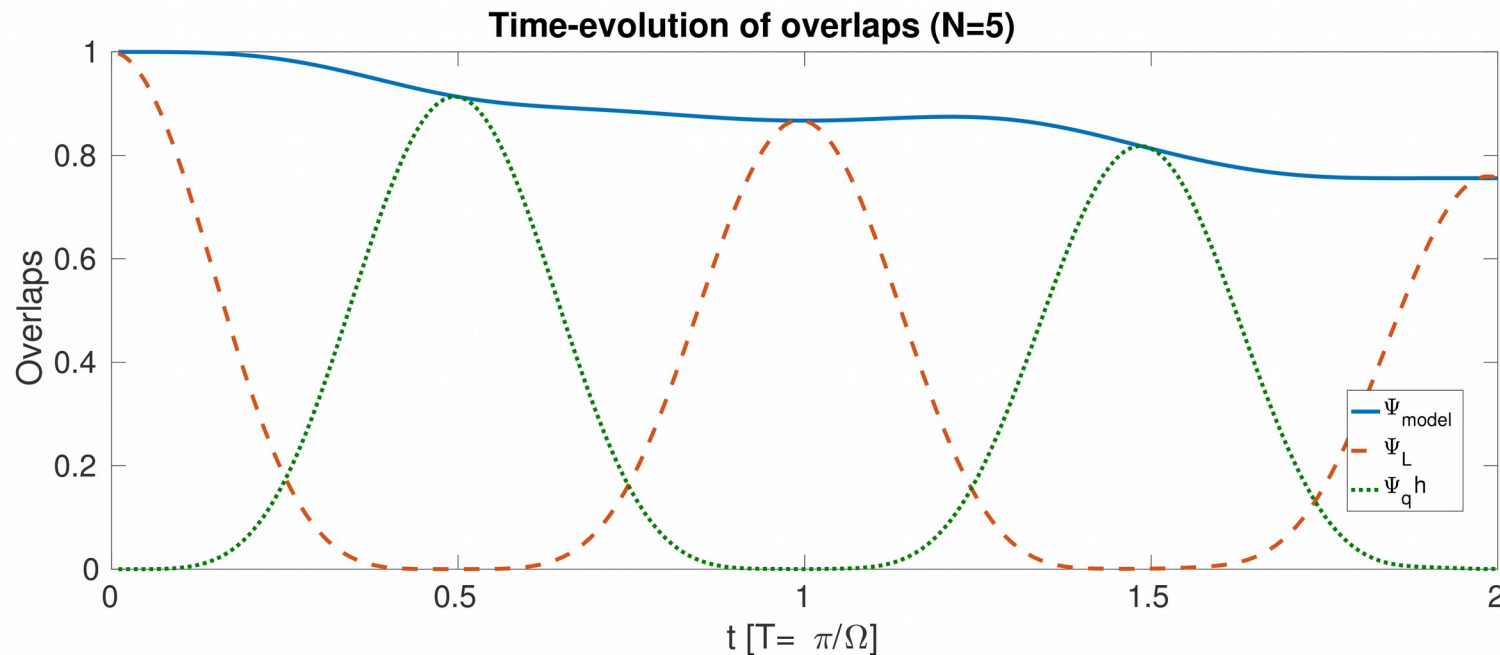
Overlap of $\Psi(t=T/2)$ with quasihole state



Time evolution in the light field

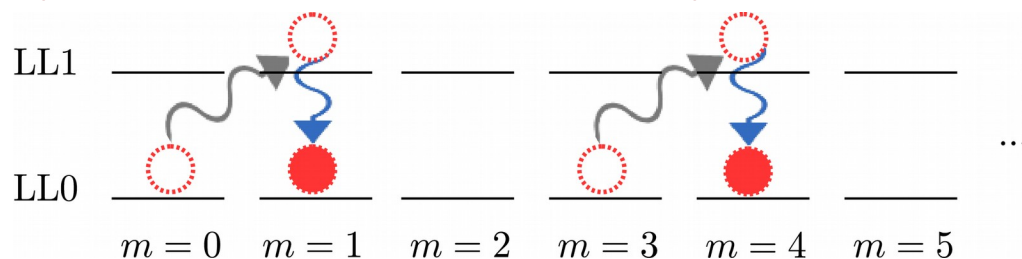
can be modeled as superposition of initial state, quasihole state, and edge-like excitations:

$$\Psi_{\text{model}}(t) = \sum_{s=0}^N \sqrt{\binom{N}{s}} \cos(\Omega t)^{N-s} \sin(\Omega t)^s \Psi^{(s)}, \quad \Psi^{(s)} \sim \sum_{\{k_1, \dots, k_s\}} \frac{1}{\sqrt{\binom{N}{s}}} \prod_{j=1}^s a_{k_j}^\dagger b_{k_j}^\dagger \Psi_L.$$



Orthogonality catastrophe:
Fine tuning?

Spontaneous emission: Raman pulses



Trapping quasiholes with light

Potential from AC Stark shift of a Gaussian light beam:

$$V_{\text{opt}}^{(\xi, w)}(z) = \frac{I(z)}{\Delta} = \left(\frac{l_B}{w}\right)^2 V_{\text{opt},0} \exp\left[-\frac{(z - \xi)^2}{w^2}\right]$$

Center of the beam width of the beam
~ microns

For AMO systems: magnetic length of the order of microns → delta-potential supports quasihole excitations

VOLUME 87, NUMBER 1

PHYSICAL REVIEW LETTERS

2 JULY 2001

$\frac{1}{2}$ -Anyons in Small Atomic Bose-Einstein Condensates

B. Paredes,* P. Fedichev, J.I. Cirac, and P. Zoller

New Journal of Physics

The open access journal at the forefront of physics

PAPER

Fractional quantum Hall states of a few bosonic atoms in geometric gauge fields

B Juliá-Díaz^{1,2,4}, T Graß², N Barberán¹ and M Lewenstein^{2,3}

Published 1 May 2012 • IOP Publishing and Deutsche Physikalische Gesellschaft

[New Journal of Physics, Volume 14, May 2012](#)

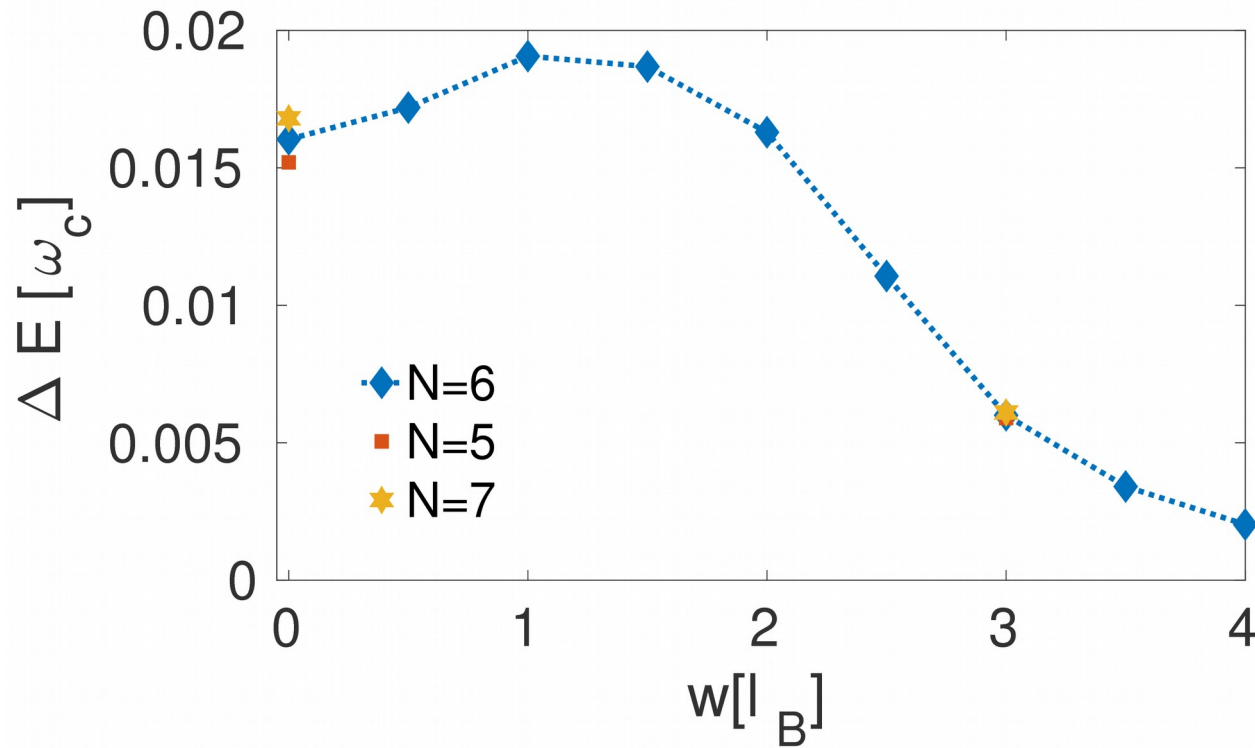
[Focus on Bose Condensation Phenomena in Atomic and Solid State Physics](#)

Electronic systems: $w \gg l_B = 26\text{nm}/\sqrt{B[\text{in T}]}$

Can broad potentials still trap quasiholes?

Trapping quasiholes with light

Even for broad potentials, the quasihole state is favored (high overlaps), but the energy gap to other states becomes small:



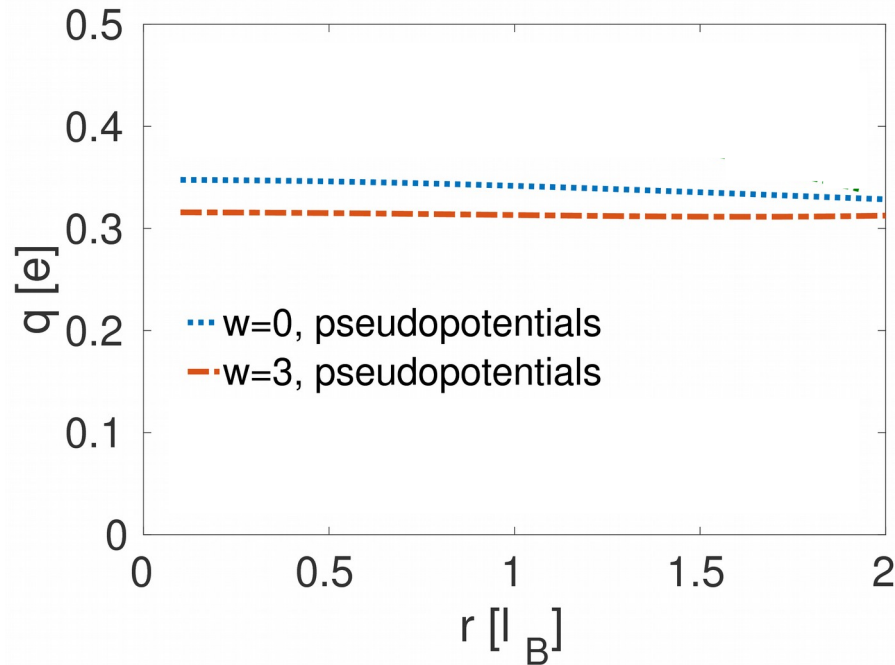
ED for system at filling $1/3$ on the torus.

Moving quasiholes with light

Berry phase for moving the quasihole adiabatically on closed loop: $\gamma = \oint d\xi \langle \Psi(\xi) | \nabla_{\xi} | \Psi(\xi) \rangle$

Berry phase is related to the charge q of the quasihole: $\frac{q}{e} = \gamma \frac{l_B^2}{A}$.

We can extract Berry phase from ground states at different quasihole positions:



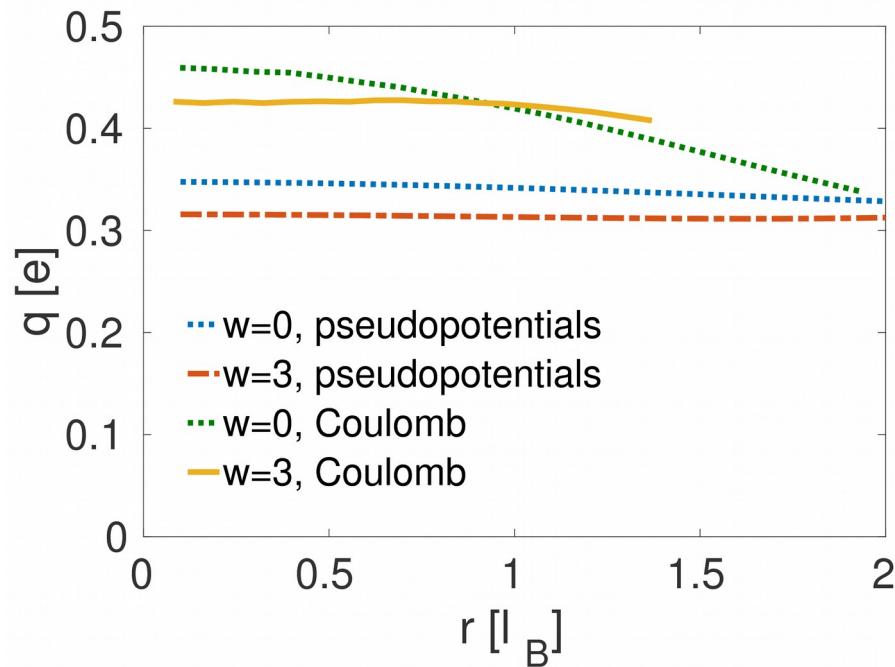
ED for system on disk in a Laughlin-like phase:
Broadness of potential does not spoil the charge of the quasihole.

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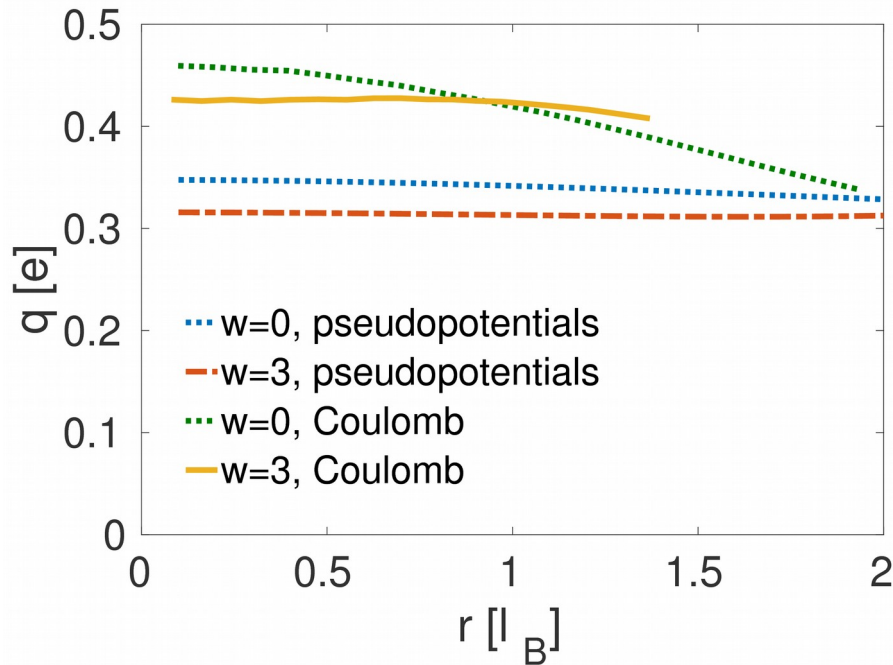
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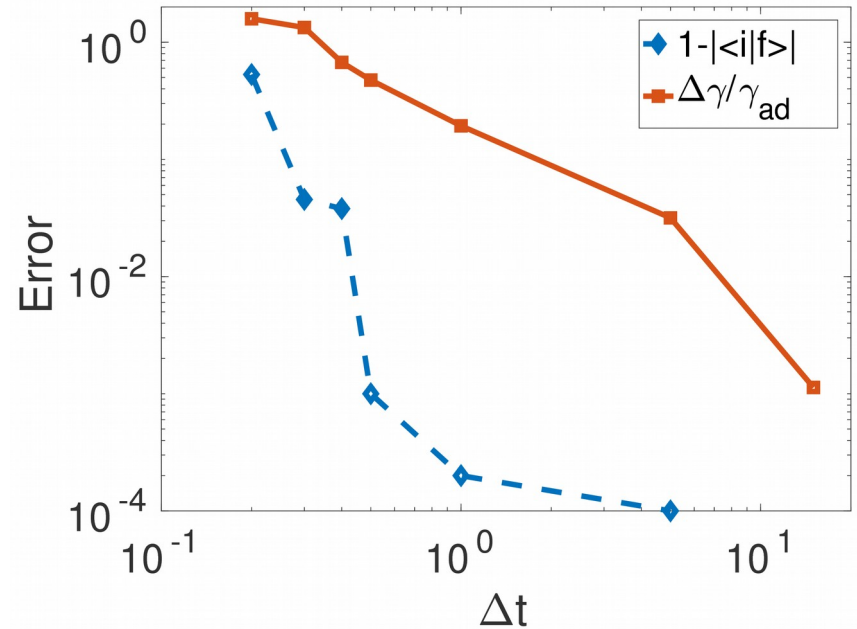
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ED for system on disk in a Laughlin-like phase: Broadness of potential does not spoil the charge of the quasihole.

Or we can extract Berry phase from time evolution while the potential moves:



Discretized in 200 step. Error as a function of step duration. Phase error (red curve) is large.

Summary

Part I: Optical driving.

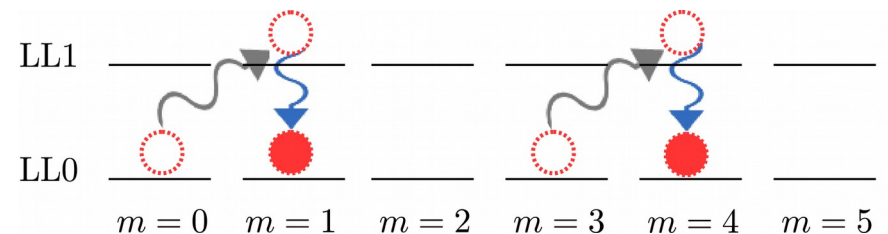
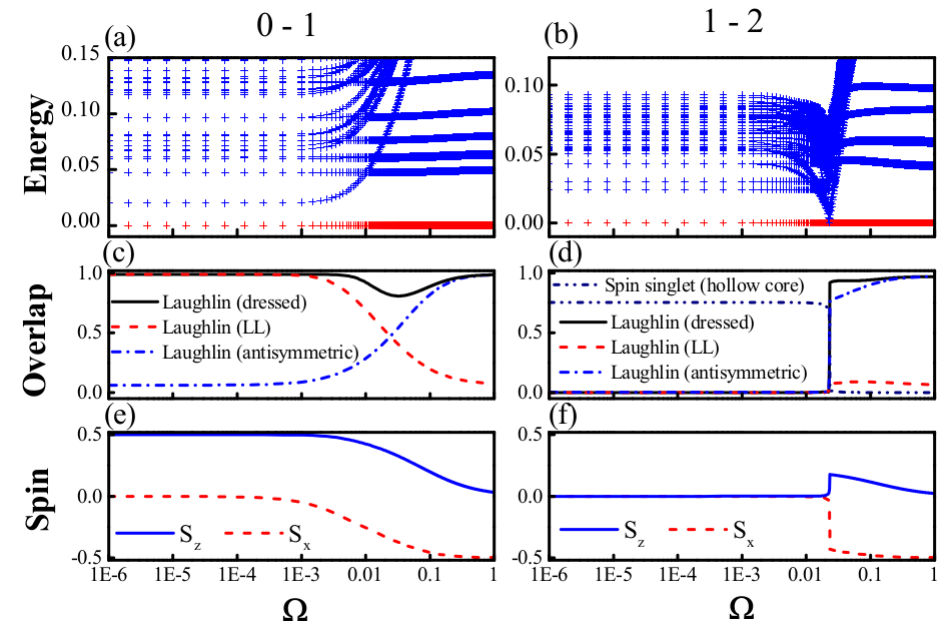
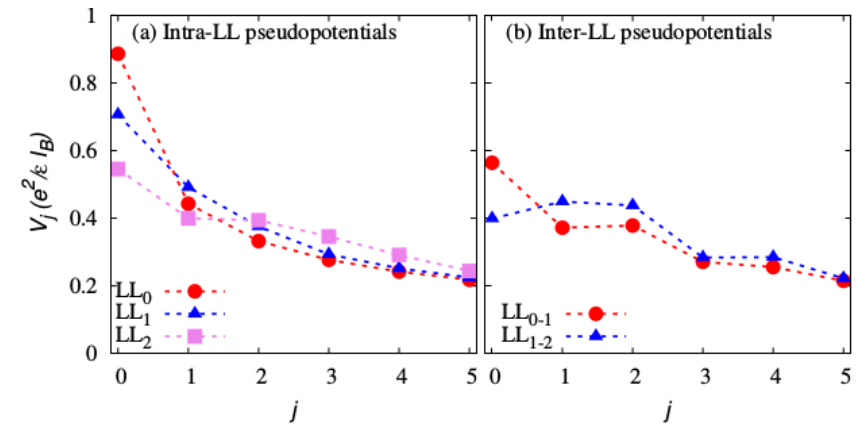
Areg Ghazaryan, Tobias Graß, Michael J. Gullans, Pouyan Ghaemi, and Mohammad Hafezi, Phys. Rev. Lett. 119, 247403 (2017)

- Synthetic bilayer: Interactions are potentially very different from interactions in real bilayers.
- Transition to exotic FQH phases:
 - non-Abelian Fibonacci phase at filling 2/3
 - Haldane-Rezayi phase at filling 1/2 ?

Part II: Optical excitations.

to appear on arXiv soon

- Light pulse with OAM produces (quasi)holes.
- Despite their broadness, laser beams can pin quasiholes.



Thank you!